# NSN 5962-01-107-2482

Memory Microcircuit - Page 1 of 1



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# Body Length:

0.840 inches

## Body Width:

Between 0.220 inches and 0.310 inches

## **Body Height:**

0.185 inches

### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

### **Features Provided:**

Hermetically sealed and burn in and programmable and 3-state output

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

10 input

Case Outline Source And Designator:

D-2 mil-m-38510

#### **Terminal Surface Treatment:**

Solder

### Voltage Rating And Type Per Characteristic:

7.0 volts power source

### **Time Rating Per Chacteristic:**

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output

### Memory Device Type:

Rom

### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

### Terminal Type And Quantity:

16 printed circuit

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

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